

10Gbit/s X2 LRM Transponder (TRP10GDL0603)

Features

- Support X2 MSA Rev. 2.0b
- Support IEEE 802.3aq-2006 10GBASE-LRM at 10.3125Gbit/s (TRP10GDP0303)
- Typical transmission distance up to 220 m over MMF
- Low Power Consumption 3.2 W (typ.)
- 0°C 70°C case operating temperature range
- Laser Class 1 IEC / CDRH compliant
- SC duplex connector
- Uncooled 1310nm DFB Laser
- Hot pluggable 70-pin connector with XAUI electrical interface
- Management and control via MDIO 2-wire interface
- Complaint with the EU RoHS 6 Environmental requirements



General Description and Applications

The TRP10GDL0603 is a highly integrated, serial optical transponder module for high-speed, 10Gbit/s data transmission applications. The module is fully compliant to IEEE 802.3aq-2006

Standard	Description	Nominal Baud Rate	Unit
IEEE 802.3aq-2006	10 GBASE-LRM	10.3125	GBd

standard for Ethernet, making it ideally suited for 10 GbE datacom (rack-to-rack, client interconnection) applications. Designed for distances of up to 220m over legacy multimode fibers, the transponder module comprises a transmitter with a directly modulated uncooled 1310nm DFB laser, a receiver with a PIN photodiode, a XAUI-Attachment Interface, an integrated Coder / Decoder and multiplexer / demultiplexer (SERDES: Serializer / Deserializer). The transponder operates within a wide case temperature range of 0 °C to +70°C and offers optimum heat dissipation and excellent electromagnetic shielding which enables high port densities for 10 GbE systems. A 70 pin electrical connector and a duplex SC connector optical interface assure that connectivity is compliant to the X2 and XENPAK MSA.



Absolute Maximum Ratings

Rating	Conditions/Remark	Symbol	Min	Max	Units
Storage Ambient Temperature	non condensing	$\vartheta_{\sf stg}$	-40	+85	∞
Powered Case Temperature	non condensing	ϑ_{c}	-10	+75	∞
Adaptable Power Supply (APS)	Voltage @ Pin APS Sense	V _{APSsense}	-0.3	1.5	V
Supply Voltage 3.3V Rail		V _{CC3}	-0.3	3.8	V
Supply Voltage 5V Rail		V _{CC5}	-0.5	7.0	V
Input Voltage Low Speed Signals	RESET, TxOn/Off, PRTADR40	Vı		tbd	V
Clamp Currents Low Speed Signals	RESET, TxOn/Off, PRTADR40 V<0V	I _{IK}		tbd	mA
LASI Voltage		VQ	-0.3	1.5	V
LASI Sink Current	Continuous Sink Current	I _{QL}		20	mA
XAUI Input Level		V _{IXAUI}	-0.3	1.8	V
Differential XAUI Input Amplitude		V _{IDXAUI}		tbd	mV
Optical Receiver Input Power	Average Receiver Input Power	P _{Rx}		+4	dBm
Static Discharge Voltage	MIL STD 883 Method 3015.1			500	V

Any stress beyond the maximum ratings can result in permanent damage. The device specifications are guaranteed only under the recommended operating conditions.

Recommended Operating Conditions

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Parameter	Conditions / Remark	Symbol	Min	Тур	Max	Units
Operating Case Temperature Range		ϑ_{Case}	0		+70	Ŝ
APS Voltage ¹⁾²⁾		V _{APS}	0.95	1.0	1.05	V
Power Supply Voltage @ 3.3V		V _{CC3}	3.135	3.3	3.465	V
Power Supply Voltage @ 5.0V		V _{CC5}	4.75	5.00	5.25	V

¹⁾ The device is supposed to operate in the APS control environment described and specified in the XENPAK-MSA (page 22 to 24 of Revision 3.0). In this environment the APS-Sense Voltage requirements will be automatically satisfied if APS-Feedback Voltage is within its recommended range. The operating APS-Sense Voltage is for informational purposes and is subject to be changed without further notice.

2) A more detailed description on the APS control circuit can also be found on page Fehler! Textmarke nicht definiert..



Electrical Characteristics

Parameter	Conditions	Symbol	Min	Тур	Max	Units
5V Supply Current	$P_{Rx} = 0 \dots \underline{0.5} \dots 1.125 mW$	I _{VCC5}	0.38	2	3	mA
3.3V Supply Current	RESET=H, TxOn/Off = H	I _{VCC3}	310	390	590	mA
APS Supply Current	V _{Feedback} = 785800812mV	I _{VCCAPS}	550	1950	2200	mA
APS-Input Capacitance		C _{APS}		tbd		μF

XAUI - Interface

XAUI Input Characteristics

Parameter	Conditions	Symbol	Min	Тур	Max	Units
Data Rate	10GBASE-LRM module			3.125		GBd
	Relative Tolerance		-100		+100	ppm
Single Ended Input Voltage Swing		V_{ID}	100			mV_{P-P}
Differential Return Loss	100MHz – 2.5GHz	SDD11	10			dB
Total Peak-to-Peak Jitter Tolerance	Sinusoidal Jitter @ 0 20MHz	T _{jRDS}	0.65			UI
Differential Input Impedance		R _{IND}	80	100	120	Ω

Note: XAUI-input-Lanes are ac-inputs.

XAUI Output Characteristics

Parameter	Conditions	Symbol	Min	Тур	Max	Units
XAUI Data Rate	10GBASE-LRM module			3.125		GBd
	XAUI Data Rate Tolerance		-100		+100	ppm
Single Ended Output Voltage Swing	$R_{LOAD} = 100\Omega \pm 5\%$		400		800	mV _{P-P}
Differential Output Impedance		R_{QD}	80	100	120	Ω
Differential Transition Time	20% - 80%		60		130	ps
Total Peak to Peak Jitter					0.27	UI

Note: XAUI-output-Lanes are ac-outputs.



Optical Interface

Recommended Operating Conditions

Parameter	Remark	Symbol	Min	Тур	Max	Units
Operating Range	62.5 um MMF OM1 50um MMF OM2 50um MMF OM3	I _{OP}		0.5 to 220 0.5 to 220 0.5 to 220		m
Input Data Rate	10GBASE-LRM module	DR₀		10.3125		Gbd
	relative tolerance	$\Delta DR/DR_{typ}$	-100		+100	ppm
Receiver Input Signal	Center Wavelength	λc	1,260	1,310	1,360	nm

Transmitter Characteristics

if not otherwise mentioned under recommended operating conditions and standard compliant single mode fiber.

Characteristic	Conditions	Symbol	Min	Тур	Max	Units
Data Rate	10GBASE-LRM module	DR		10.3125		Gbps
	relative tolerance to nominal DR	$\Delta \text{DR/DR}_{\text{typ}}$	-100		100	ppm
Nominal Wavelength		λ_{TRP}	1,260	1,310	1,355	nm
Spectral Width	referred to -20dB points	Δλ			0.2	nm
Side Mode Suppression Ratio		SMSR	30			dB
Optical Output Power		Pout	-6.5		0.5	dBm
Extinction Ratio	EOL	ER	3.5	8		dB
Optical Modulation Amplitude		OMA	-4.5		0.5	dBm
Relative Intensity Noise		RIN			-128	dB/Hz

Receiver Characteristics

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if not otherwise mentioned under recommended operating conditions and standard compliant single mode fiber.

Parameter	Conditions	Symbol	Min	Тур	Max	Units
Stressed Receiver Sensitivity	OMA	P _{INpp}	-6.5			dBm
Stressed Receiver Sensitivity Symetrical test	OMA	P _{INpp}	-6			dBm
Saturation Input Power	OMA	P _{SAT}	1.5			dBm
SD Deasserted ¹		P _{SDD}	-30			dBm
SD Hysteresis ¹		h _{SD}	0.5			dB
Optical Return Loss		ORL			-12	dB

Note 1: SD-Level is available at D0 from the 10G PMD Receive Signal Detect Register 1.10.



MDIO Interface

DC Characteristics

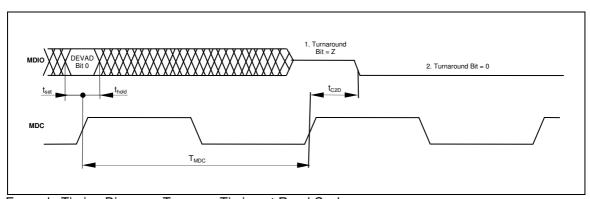
if not otherwise mentioned under the recommended operating conditions

Characteristic	Condition	Symbol	Minimum	Maximum	Unit
Input high voltage		V _{IH}	0.84	1.5	V
Input low voltage		V_{IL}	-0.3	0.36	V
MDIO Input current	MMD Driver in tri-state	I _{IMDIO}	-5	5	μΑ
MDC Input current		I _{IMDC}	-5	5	μΑ
Output low voltage	$I_{OL} = 100 \mu A$	V_{QL}	-0.3		V
	$I_{OL} = 4mA$	V_{QL}		0.2	V
Output high voltage	$I_{0H} = -100 \mu A$				
	$R_{PULL-Up} = 357\Omega \pm 1\%$	V_{QH}	0.95	1.5	V
	$V_{PULL-Up} = 0.951.5V$				
Output low current	$V_I = 0.2V$	I_{QL}	+4		mA
MDIO Input capacitance	$V_1 = 01.5V$	Cin		10	pF

AC Characteristics

if not otherwise mentioned under the recommended operating conditions. Furthermore its recommended that clock period time T_{MDC} is not less than 310ns and the sum of input currents of loads on the bus does not exceed 256µA at high and at low not below -320µA.

Characteristic	Condition	Symbol	Minimum	Maximum	Unit
Set Up Time		t _{set}		10	ns
Hold Time		t _{hold}		10	ns
Clock to Data Time	R _{PULL-Up} = 357Ω ±1%, C _{BUS} ≤470pF	t _{C2D}	0	300	ns



Example Timing Diagram: Turnover Timing at Read Cycle



Electro Static Discharge (ESD)

The maximum electrostatic charge based on a human body model and the conditions as outlined below is:

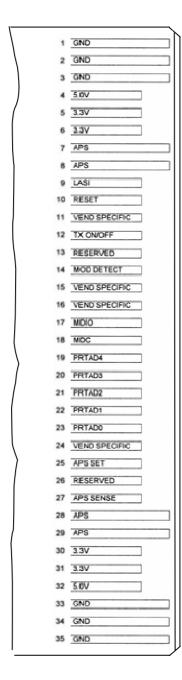
Parameter	Conditions	Symbol	Min	Тур	Max	Units
Static Discharge Voltage	MIL STD 883 Method 3015.1			500	V	

Thermal Management

The transponder is designed for an operation within a case temperature range between 0 to $+70\,^{\circ}\text{C}$ at an altitude of < 3km. The built in heatsink provides an optimized thermal performance. The user needs to guarantee per system design not to exceed this temperature range. It has to be considered that in case of usage of multiple modules on a single hostboard that there is a temperature rise among the modules hosted side by side (see figure below). Airflow direction and air speed needs to be choosen accordingly. For further information it is referred to the MSA document.



Card-Edge-Connector-Pinning and Layout



70	GND
69	GND
68	
67	RESERVED
66	GND
65	TX LANE3-
64	TX LANE3+
63	GND
62	TX LANE2-
61	TX LANE2+
60	GND
59	TX LANE1-
58	TX LANE1+
57	GND
56	TX LANEO-
55	TX LANE0+
54	GND
53	GND
52	GND
51	RX LANE3-
50	RX LANE3+
49	GND
48	RX LANE2-
47	RX LANE2+
45	GND
	RX LANE1-
	RX LANE1+
43	GND
	RX LANEO-
	RX LANE0+
	GND
	RESERVED
	RESERVED
	GND
36	GND

Top view -Top side

Top view-Bottom row (as seen through PCB)



Electrical Pin Definition – Pins 01 to 40 of 70

Symbol	Logic	PIN	Name / Description	Note
3.3V		5, 6, 30, 31	Power Supply of Optical Receiver and Transmitter and Control Circuits	2
5.0V		4, 32	Power Supply of Optical Receiver Frontend	2
APS		7, 8, 28, 29	Adaptive Power Supply, Supply of PHY XS and PCS Layer Devices	2
APS SENSE		27	APS Sense Output for APS Control Circuit	
APS SET		25	Feedback Input for APS, Input of APS Setting Resistor	
GND		1, 2, 3, 33, 34, 35, 36, 37, 40, 43, 46, 49, 52, 53, 54, 57, 60, 63, 66, 69, 70	S, B, Common Electrical Ground	
LASI	1.2V CMOS Open Drain Output	9	Link Alarm Status Interrupt, low active, Open Drain Output Supposed to operate with $10K\Omega$ - $22K\Omega$ pull upon host. Logic High: Normal Operation Logic Low: Link Alarm is indicated	
MDC		18	Management Clock Input	3
MDIO		17	Management Data IO	3
MOD DETECT		14	1kΩ to Ground for APS Circuit Environment	
PRTADO	1.2V CMOS Input	23	Port Address Bit 0 (Low = 0), internally pulled up by $18k\Omega$	
PRTAD1	1.2V CMOS Input	22	Port Address Bit 1 (Low = 0), internally pulled up by $18k\Omega$	
PRTAD2	1.2V CMOS Input	21	Port Address Bit 2 (Low = 0), internally pulled up by $18k\Omega$	
PRTAD3	1.2V CMOS Input	20	Port Address Bit 3 (Low = 0), internally pulled up by $18k\Omega$	
PRTAD4	1.2V CMOS Input	19	Port Address Bit 4 (Low = 0), internally pulled up by $18k\Omega$	
RESERVED		13, 38, 39, 67, 68	Reserved by MSA, internally not connected	
RESERVED		26	Reserved for Avalanche Photodiode use, internally not connected	
RESET	1.2V CMOS Input	10	Low active Reset Input 10KΩ pull-up on Transceiver Logic high = Normal Operation Logic Low = Reset asserted	
TX ON/OFF	1.2V CMOS Input	12	High active Transmitter Enable Input 10KΩ pull-up on Transceiver Logic high = Transmitter active (normal Operation) And Register Bit 1.9.0 set to low as well Logic Low = shut down of Transmitter	
VENDSPECIFIC		11, 15, 16, 24	Vendor Specific Pin,. for proper operation leave unconnected	5



Electrical Pin Definition - Pins 41 to 70 of 70

Symbol	Logic	PIN	Name / Description	Note
RX LANE0+		41	Module XAUI Output Lane 0+	4
RX LANE0-		42	Module XAUI Output Lane 0-	4
RXLANE1+		44	Module XAUI Output Lane 1+	4
RXLANE1-		45	Module XAUI Output Lane 1-	4
RX LANE2+		47	Module XAUI Output Lane 2+	4
RX LANE2-		48	Module XAUI Output Lane 2-	4
RX LANE3+		50	Module XAUI Output Lane 3+	4
RX LANE3-		51	Module XAUI Output Lane 3-	4
TX LANE0+		55	Module XAUI Input Lane 0+	4
TX LANE0-		56	Module XAUI Input Lane 0-	4
TXLANE1 +		58	Module XAUI Input Lane 1+	4
TXLANE1-		59	Module XAUI Input Lane 1-	4
TX LANE2+		61	Module XAUI Input Lane 2+	4
TX LANE2-		62	Module XAUI Input Lane 2-	4
TX LANE3+		64	Module XAUI Input Lane 3+	4
TX LANE3-		65	Module XAUI Input Lane 3-	4

- 1) Ground connections are common for TX and RX.
- Each connector contact is rated at 0.5A.
- 2) 3) MDIO and MDC timing must comply with IEEE 802.3ae clause 45.3.
- XAUI output characteristics comply with IEEE 802.3ae clause 47. 4)
- Transceivers will be MSA compliant when no signals are present on the vendor specific pins



Eye Safety

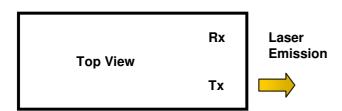
This laser based multimode transceiver is a Class 1 product. It complies with IEC 60825-1/A2: 2001 and FDA performance standards for laser products (21 CFR 1040.10 and 1040.11) except for deviations pursuant to Laser Notice 50, dated July 26, 2001.

CLASS 1 LASER PRODUCT

To meet laser safety requirements the transceiver shall be operated within the Absolute Maximum Ratings.

Note: All adjustments have been made at the factory prior to shipment of the devices. No maintenance or alteration to the device is required. Tampering with or modifying the performance of the device will result in voided product warranty. Failure to adhere to the above restrictions could result in a modification that is considered an act of "manufacturing", and will require, under law, recertification of the modified product with the U.S. Food and Drug Administration (ref. 21 CFR 1040.10 (i)).

Laser Emission Data



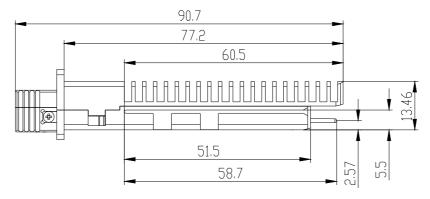
Wavelength	1310 nm
Maximum total output power (as defined by IEC: 7 mm aperture at 14 mm distance)	15.6 mW / 11.9 dBm
Beam divergence (full angle) / NA (half angle)	11°/0.1 rad

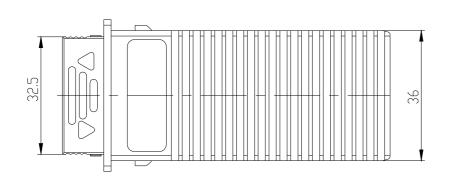
Required Labeling

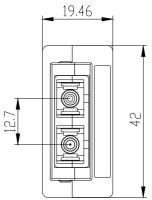




Mechanical Drawing









Order Information

